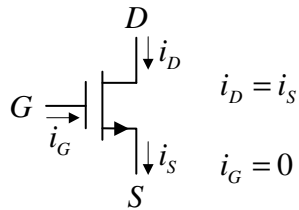


## Režimi rada MOS tranzistora

### ➤ NMOS tranzistor



#### ❖ Zasićenje:

$$v_{GS} > V_{TN} \text{ i } v_{GD} < V_{TN}$$

$$i_D = \frac{B}{2} (v_{GS} - V_{TN})^2 = \frac{\mu_n C_{ox} W}{2L} (v_{GS} - V_{TN})^2; \quad B = \frac{\mu_n C_{ox} W}{L}$$

#### ❖ Triodna oblast:

$$v_{GS} > V_{TN} \text{ i } v_{GD} > V_{TN}$$

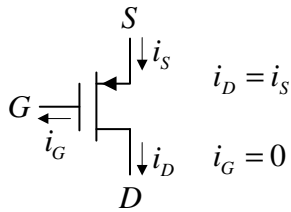
$$i_D = B \left[ (v_{GS} - V_{TN})v_{DS} - \frac{v_{DS}^2}{2} \right] = \frac{\mu_n C_{ox} W}{L} \left[ (v_{GS} - V_{TN})v_{DS} - \frac{v_{DS}^2}{2} \right]; \quad B = \frac{\mu_n C_{ox} W}{L}$$

#### ❖ Zakočenje (OFF):

$$v_{GS} < V_{TN}$$

$$i_D = 0$$

➤ PMOS tranzistor



❖ Zasićenje:

$$v_{SG} > |V_{TP}| \text{ i } v_{DG} < |V_{TP}|$$

$$i_D = \frac{B}{2} (v_{SG} - |V_{TP}|)^2 = \frac{\mu_p C_{ox} W}{2L} (v_{SG} - |V_{TP}|)^2; \quad B = \frac{\mu_p C_{ox} W}{L}$$

❖ Triodna oblast:

$$v_{SG} > |V_{TP}| \text{ i } v_{DG} > |V_{TP}|$$

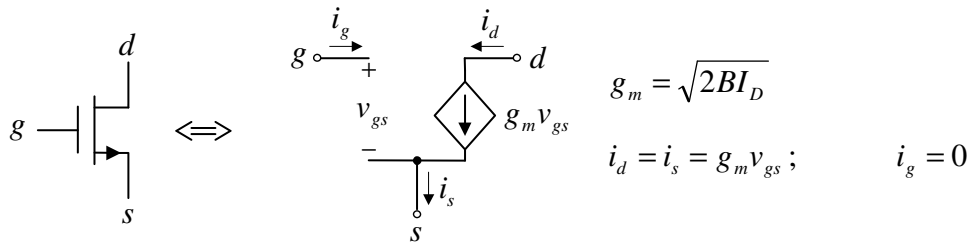
$$i_D = B \left[ (v_{SG} - |V_{TP}|) v_{SD} - \frac{v_{SD}^2}{2} \right] = \frac{\mu_p C_{ox} W}{L} \left[ (v_{SG} - |V_{TP}|) v_{SD} - \frac{v_{SD}^2}{2} \right]; \quad B = \frac{\mu_p C_{ox} W}{L}$$

❖ Zakočenje (OFF):

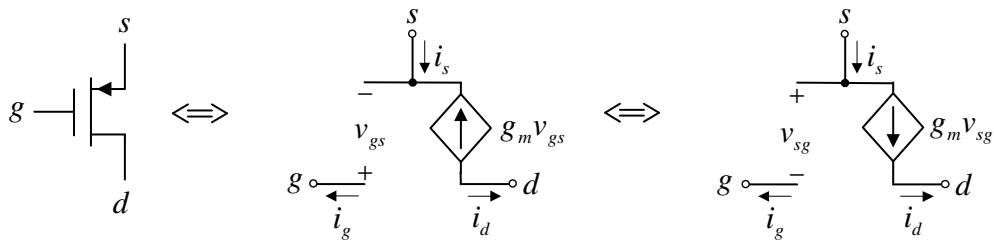
$$v_{SG} < |V_{TP}|$$

$$i_D = 0$$

➤ Model NMOS tranzistora za mali signal:



➤ Model PMOS tranzistora za mali signal:

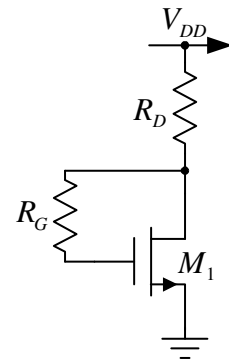


$$g_m = \sqrt{2BI_D}; \quad i_d = i_s = g_m v_{sg}; \quad i_g = 0$$

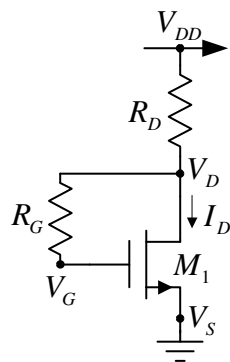
89. Parametri tranzistora u kolu sa slike su:  $V_{TN} = V_T = 3V$  i

$$B = \frac{\mu_n C_{ox} W}{L} = 0,48 \text{mA/V}^2, \text{ dok je } V_{DD} = 12V, R_D = 2k\Omega \text{ i } R_G = 10M\Omega.$$

Izračunati napone  $V_{GS}$  i  $V_{DS}$ .



**Rešenje:**



Pretpostavka  $M_1$  u zasićenju:

$$\left. \begin{aligned} I_D &= \frac{B}{2}(V_{GS} - V_T)^2 \\ V_{GS} &= V_G = V_D = V_{DD} - R_D I_D \end{aligned} \right\} \Rightarrow I_D = \frac{B}{2}(V_{DD} - R_D I_D - V_T)^2$$

$$I_D = 0,00024 \cdot (9 - 2000 I_D)^2$$

$$960I_D^2 - 9,64I_D + 0,01944 = 0$$

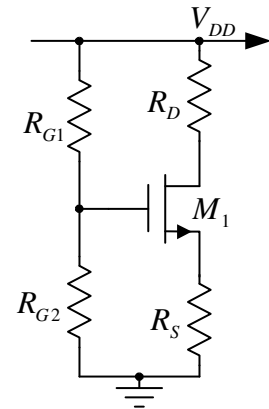
$I_D' = 7,25\text{mA} \Rightarrow V_{GS}' = V_{DD} - R_D I_D' = -2,5\text{V} < V_T \Rightarrow$  odbacuje se jer je  $M_1$  po postavljenoj pretpostavci u zasićenju

$I_D'' = 2,79\text{mA} \Rightarrow V_{GS}'' = V_{DD} - R_D I_D'' = 6,42\text{V} > V_T \Rightarrow$  prihvata se jer je u skladu sa postavljenom pretpostavkom da je  $M_1$  u zasićenju

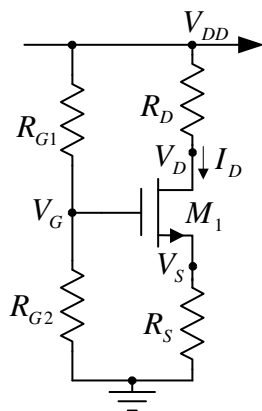
Dakle:  $I_D = 2,79\text{mA}$ ,  $V_{GS} = 6,42\text{V} > V_T$ ,  $V_{GD} = 0 < V_T$ , što znači da je  $M_1$  zaista u zasićenju, tj. pretpostavka je tačna.

$$V_{GS} = V_{DS} = 6,42\text{V}$$

**90.** Parametri tranzistora u kolu sa slike su:  $V_{TN} = V_T = 1\text{V}$  i  $B = \frac{\mu_n C_{ox} W}{L} = 1\text{mA/V}^2$ , dok je  $V_{DD} = 10\text{V}$ ,  $R_{G1} = R_{G2} = 10\text{M}\Omega$  i  $R_D = R_S = 6\text{k}\Omega$ . Izračunati struju  $I_D$ , kao i napone  $V_G$ ,  $V_D$  i  $V_S$ .



**Rešenje:**



Pretpostavka  $M_1$  u zasićenju:

$$\left. \begin{aligned} I_D &= \frac{B}{2} (V_{GS} - V_T)^2 \\ V_{GS} = V_G - V_S &= \frac{R_{G2}}{R_{G1} + R_{G2}} V_{DD} - R_S I_D = \frac{V_{DD}}{2} - R_S I_D \end{aligned} \right\} \Rightarrow$$

$$I_D = \frac{B}{2} \left( \frac{V_{DD}}{2} - R_S I_D - V_T \right)^2 \Rightarrow I_D = 0,0005 \cdot (4 - 6000 I_D)^2$$

$$18000I_D^2 - 25I_D + 0,008 = 0$$

$I_D' = 0,889\text{mA} \Rightarrow V_{GS}' = \frac{V_{DD}}{2} - R_S I_D' = -0,334\text{V} < V_T \Rightarrow$  odbacuje se jer je  $M_1$  po postavljenoj pretpostavci u zasićenju

$I_D'' = 0,5\text{mA} \Rightarrow V_{GS}'' = \frac{V_{DD}}{2} - R_S I_D'' = 2\text{V} > V_T \Rightarrow$  prihvata se jer je u skladu sa postavljenom pretpostavkom da je  $M_1$  u zasićenju

Dakle:  $I_D = 0,5\text{mA}$ ,  $V_{GS} = 2\text{V} > V_T$ ,  $V_{GD} = V_G - V_D = \frac{R_{G2}}{R_{G1} + R_{G2}} V_{DD} - (V_{DD} - R_D I_D) = -2\text{V} < V_T$ , što znači da je  $M_1$  zaista u zasićenju, tj. pretpostavka je tačna.

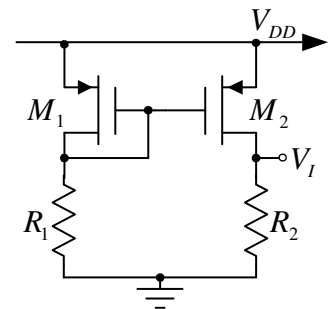
$$\boxed{I_D = 0,5\text{mA}}$$

$$V_G = \frac{R_{G2}}{R_{G1} + R_{G2}} V_{DD} = \frac{V_{DD}}{2} \Rightarrow \boxed{V_G = 5\text{V}}$$

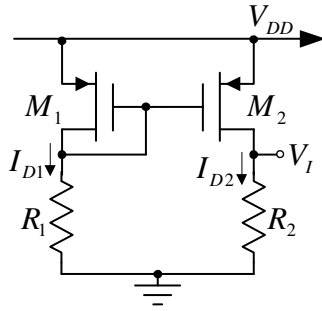
$$V_D = V_{DD} - R_D I_D \Rightarrow \boxed{V_D = 7\text{V}}$$

$$V_S = R_S I_D \Rightarrow \boxed{V_S = 3\text{V}}$$

**91.** Parametri tranzistora u kolu sa slike su:  $V_{TP} = -V_T = -1\text{V}$ ,  $B_1 = \frac{\mu_p C_{ox} W_1}{L_1} = 2\text{mA/V}^2$  i  $B_2 = \frac{\mu_p C_{ox} W_2}{L_2} = 4\text{mA/V}^2$ , dok je  $V_{DD} = 12\text{V}$ ,  $R_1 = 10\text{k}\Omega$  i  $R_2 = 4\text{k}\Omega$ . Izračunati struju drena tranzistora  $M_1$ , kao i napon  $V_I$ .



**Rešenje:**



Pretpostavka  $M_1$  i  $M_2$  u zasićenju:

$$\left. \begin{aligned} I_{D1} &= \frac{B_1}{2} (V_{SG1} - |V_{TP}|)^2 \\ V_{DD} - V_{SG1} - R_1 I_{D1} &= 0 \end{aligned} \right\} \Rightarrow V_{DD} - V_{SG1} - R_1 \frac{B_1}{2} (V_{SG1} - |V_{TP}|)^2 = 0$$
$$12 - V_{SG1} - 10(V_{SG1} - 1)^2 = 0$$
$$10V_{SG1}^2 - 19V_{SG1} - 2 = 0$$

$V'_{SG1} = -0,1V < |V_{TP}| \Rightarrow$  odbacuje se jer je  $M_1$  po postavljenoj pretpostavci u zasićenju

$V''_{SG1} = 2V > |V_{TP}| \Rightarrow$  prihvata se jer je u skladu sa postavljenom pretpostavkom da je  $M_1$  u zasićenju

$$V_{DD} - V_{SG1} - R_1 I_{D1} = 0 \Rightarrow I_{D1} = \frac{V_{DD} - V_{SG1}}{R_1} = 1\text{mA}$$

$$\left. \begin{aligned} I_{D1} &= \frac{B_1}{2} (V_{SG1} - |V_{TP}|)^2 \\ I_{D2} &= \frac{B_2}{2} (V_{SG2} - |V_{TP}|)^2 \\ V_{SG1} &= V_{SG2} \end{aligned} \right\} \Rightarrow \frac{I_{D1}}{I_{D2}} = \frac{B_1}{B_2} = \frac{1}{2} \Rightarrow I_{D2} = 2I_{D1} = 2\text{mA}$$

Dakle:  $V_{SG1} = 2V > |V_{TP}|$ ,  $V_{DG1} = 0 < |V_{TP}|$ , što znači da je  $M_1$  zaista u zasićenju;  
 $V_{SG2} = V_{SG1} = 2V > |V_{TP}|$ ,  $V_{DG2} = V_{D2} - V_{G2} = R_2 I_{D2} - (V_{DD} - V_{SG2}) = -2V < |V_{TP}|$ , što znači da je  $M_2$  zaista u zasićenju.

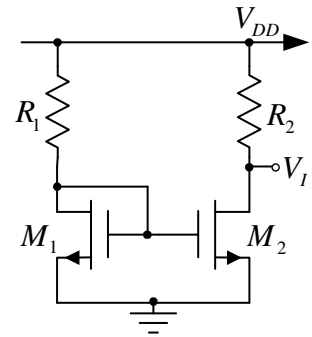
$$\boxed{I_{D1} = 1\text{mA}}$$

$$V_I = R_2 I_{D2} \Rightarrow \boxed{V_I = 8\text{V}}$$

92. (Zadatak za vežbu) Parametri tranzistora u kolu sa slike su:

$$V_{TN} = V_T = 1\text{V}, B_1 = \frac{\mu_n C_{ox} W_1}{L_1} = 2\text{mA/V}^2 \text{ i } B_2 = \frac{\mu_n C_{ox} W_2}{L_2} = 4\text{mA/V}^2,$$

dok je  $V_{DD} = 12\text{V}$ ,  $R_1 = 10\text{k}\Omega$  i  $R_2 = 4\text{k}\Omega$ . Izračunati struju drena tranzistora  $M_1$ , kao i napon  $V_I$ .



**Rešenje:**

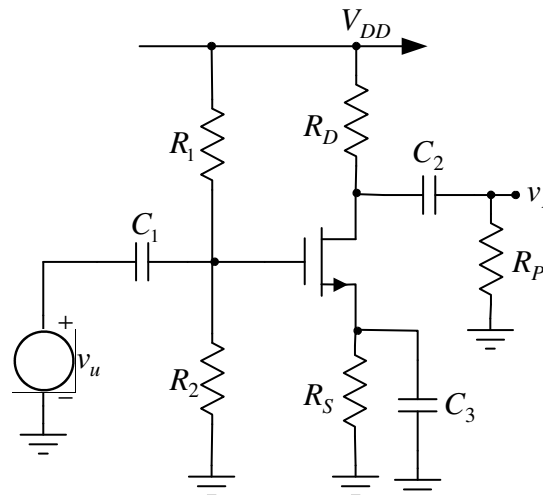
$$I_{D1} = 1\text{mA}$$

$$V_I = 4\text{V}$$

93. Za pojačavač sa slike je poznato:  $V_{DD} = 12\text{V}$ ,  $V_{TN} = V_T = 1\text{V}$ ,  $B = \frac{\mu_n C_{ox} W}{L} = 0,5\text{mA/V}^2$ ,  $C_1 \rightarrow \infty$ ,  $C_2 \rightarrow \infty$ ,  $C_3 \rightarrow \infty$ ,  $R_1 = 20\text{k}\Omega$ ,  $R_2 = 10\text{k}\Omega$ ,  $R_D = 4\text{k}\Omega$ ,  $R_S = 1\text{k}\Omega$  i  $R_P = 4\text{k}\Omega$ .

a) Izračunati jednosmernu struju drena ( $I_D$ ) i jednosmerne napone tranzistora ( $V_G$ ,  $V_S$  i  $V_D$ ).

b) Izračunati naponsko pojačanje pojačavača  $a_v = \frac{v_i}{v_u}$ , ulaznu otpornost koju vidi generator naizmeničnog signala  $v_u$  i izlaznu otpornost koju vidi potrošač  $R_P$ .

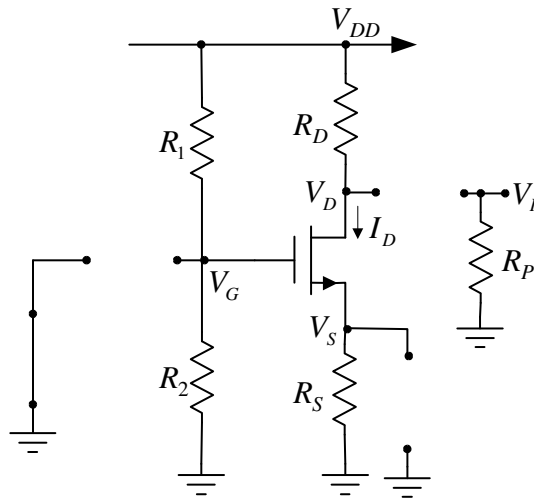


## Rešenje:

a) DC analiza:

Formiranje šeme za DC analizu:

- ukidanje svih naizmeničnih generatora;
- zamena kondenzatora otvorenim vezama.



Tranzistor je u zasićenju (preduslov da bi pojačavač ispravno radio)!

$$\left. \begin{aligned} I_D &= \frac{B}{2} (V_{GS} - V_T)^2 \\ V_{GS} = V_G - V_S &= \frac{R_2}{R_1 + R_2} V_{DD} - R_S I_D = \frac{V_{DD}}{3} - R_S I_D \end{aligned} \right\} \Rightarrow$$

$$I_D = \frac{B}{2} \left( \frac{V_{DD}}{3} - R_S I_D - V_T \right)^2 \Rightarrow I_D = 0,00025 \cdot (3 - 1000 I_D)^2$$

$$10^6 \cdot I_D^2 - 10^4 \cdot I_D + 9 = 0$$

$$I_D' = 9\text{mA} \Rightarrow V_{GS}' = \frac{V_{DD}}{3} - R_S I_D' = -5\text{V} < V_T \Rightarrow \text{odbacuje se jer } M_1 \text{ mora biti u zasićenju}$$

$$I_D'' = 1\text{mA} \Rightarrow V_{GS}'' = \frac{V_{DD}}{3} - R_S I_D'' = 3\text{V} > V_T \Rightarrow \text{prihvata se jer je u skladu sa činjenicom da } M_1 \text{ mora biti u zasićenju}$$

$$\boxed{I_D = 1\text{mA}}$$



$$V_G = \frac{R_2}{R_1 + R_2} V_{DD} = \frac{V_{DD}}{3} \Rightarrow \boxed{V_G = 4V}$$

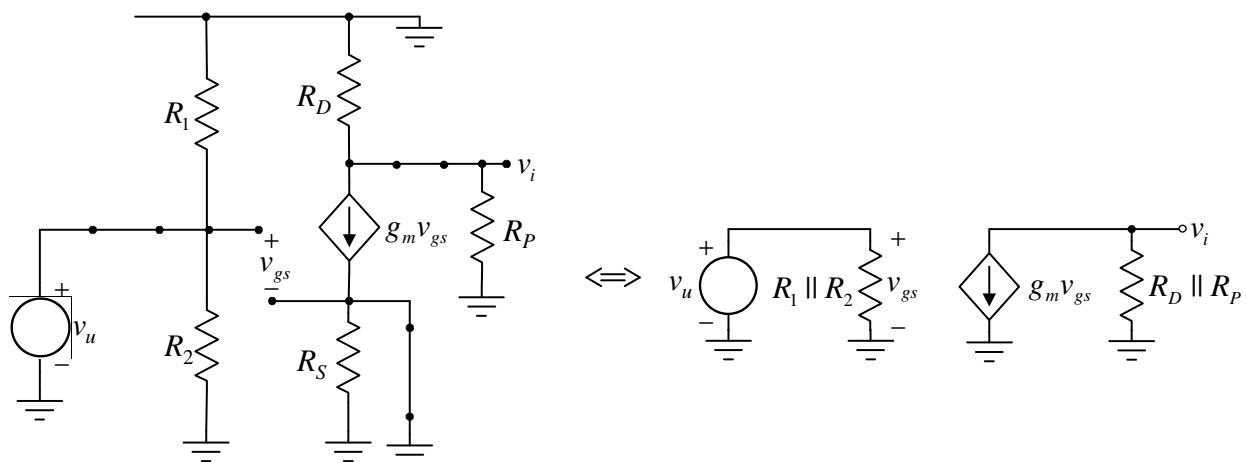
$$V_D = V_{DD} - R_D I_D \Rightarrow \boxed{V_D = 8V}$$

$$V_S = R_S I_D \Rightarrow \boxed{V_S = 1V}$$

b) AC analiza:

Formiranje šeme za AC analizu:

- ukidanje svih jednosmernih generatora;
- zamena kondenzatora  $C \rightarrow \infty$  kratkim spojevima;
- zamena tranzistora modelom za mali signal.



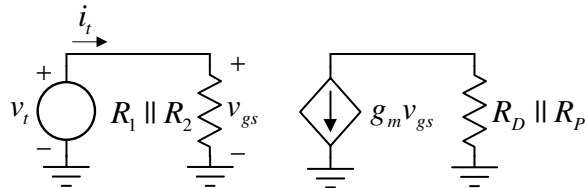
$$g_m = \sqrt{2BI_D} = 1\text{mS}$$

$$\left. \begin{array}{l} v_i = -g_m v_{gs} (R_D \parallel R_P) \\ v_{gs} = v_u \end{array} \right\} \Rightarrow v_i = -g_m v_u (R_D \parallel R_P) \Rightarrow a_v = \frac{v_i}{v_u} = -g_m (R_D \parallel R_P) \Rightarrow$$

$$\boxed{a_v = -2}$$

Šema za računanje ulazne otpornosti:

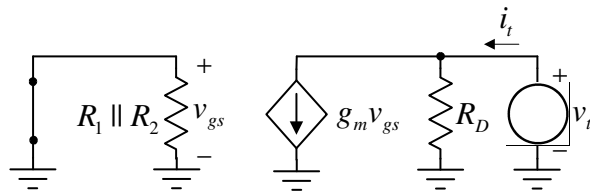
- povezivanje naponskog test generatora  $v_t$  između ulazne tačke i mase i označavanje struje  $i_t$ ;
- ukidanje svih nezavisnih generatora u ostatku kola;
- $R_{ul} = \frac{v_t}{i_t}$ ;



$$v_t = (R_1 \parallel R_2) i_t \Rightarrow R_{ul} = \frac{v_t}{i_t} = R_1 \parallel R_2 \Rightarrow \boxed{R_{ul} = 6,67\text{k}\Omega}$$

Šema za računanje izlazne otpornosti:

- povezivanje naponskog test generatora  $v_t$  između izlazne tačke i mase i označavanje struje  $i_t$ ;
- ukidanje svih nezavisnih generatora u ostatku kola;
- $R_{izl} = \frac{v_t}{i_t}$ ;

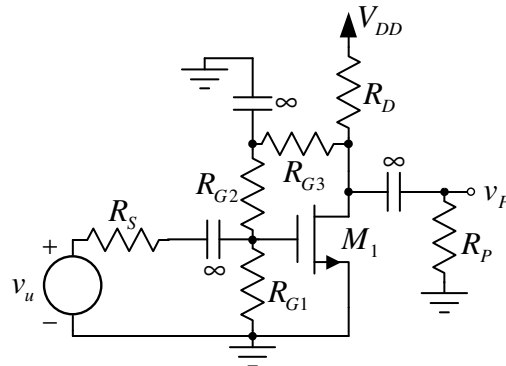


$$v_{gs} = 0 \Rightarrow g_m v_{gs} = 0 \Rightarrow v_t = R_D i_t \Rightarrow R_{izl} = \frac{v_t}{i_t} = R_D \Rightarrow \boxed{R_{izl} = 4\text{k}\Omega}$$

94. Za pojačavač sa slike je poznato:  $V_{DD} = 10V$ ,  $V_{TN} = V_T = 1V$ ,  $B = \frac{\mu_n C_{ox} W}{L} = 0,5mA/V^2$ ,  $R_{G1} = 2M\Omega$ ,  $R_{G2} = 2M\Omega$ ,  $R_{G3} = 1M\Omega$ ,  $R_D = 20k\Omega$ ,  $R_S = 10k\Omega$  i  $R_P = 100k\Omega$ .

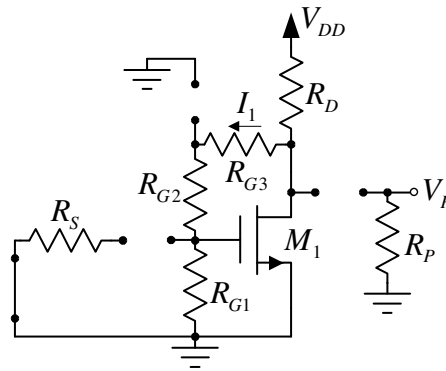
a) Izračunati jednosmernu struju drena  $I_D$  i jednosmerne napone  $V_{GS}$  i  $V_{DS}$ .

b) Izračunati naponsko pojačanje pojačavača  $a_v = \frac{v_p}{v_u}$ , ulaznu otpornost koju vidi generator naizmeničnog signala  $v_u$  i izlaznu otpornost koju vidi potrošač  $R_P$ .



### Rešenje:

a) DC analiza:



Tranzistor je u zasićenju (preduslov da bi pojačavač ispravno radio).

$$\left. \begin{aligned} V_{DS} &= V_{DD} - R_D(I_D + I_1) \\ I_1 &= \frac{V_{DS}}{R_{G3} + R_{G2} + R_{G1}} = \frac{V_{DS}}{5 \cdot 10^6} \\ I_D &= \frac{B}{2}(V_{GS} - V_T)^2 \\ V_{GS} &= \frac{R_{G1}}{R_{G3} + R_{G2} + R_{G1}} \cdot V_{DS} = 0,4V_{DS} \end{aligned} \right\} \Rightarrow V_{DS} = 10 - 2 \cdot 10^4 \cdot \left( 2,5 \cdot 10^{-4} \cdot (0,4V_{DS} - 1)^2 + \frac{V_{DS}}{5 \cdot 10^6} \right)$$

$$0,8V_{DS}^2 - 2,996V_{DS} - 5 = 0$$

$V_{DS}' \approx 5V \Rightarrow V_{GS}' = 0,4V_{DS}' \approx 2V > V_T \Rightarrow$  prihvata se jer je u skladu sa činjenicom da  $M_1$  mora biti u zasićenju

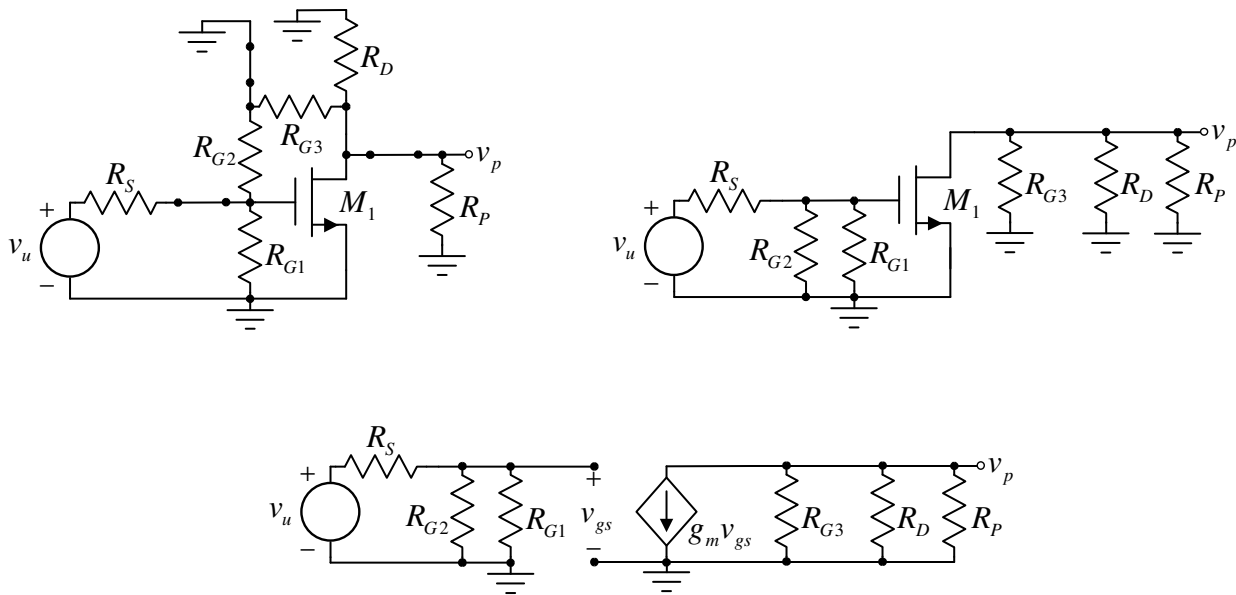
$V_{DS}'' \approx -1,25V \Rightarrow V_{GS}'' = 0,4V_{DS}'' \approx -0,5V < V_T \Rightarrow$  odbacuje se jer  $M_1$  mora biti u zasićenju

$$\boxed{V_{DS} \approx 5V}$$

$$\boxed{V_{GS} \approx 2V}$$

$$I_D = \frac{B}{2}(V_{GS} - V_T)^2 \Rightarrow \boxed{I_D \approx 250\mu A}$$

b) AC analiza:

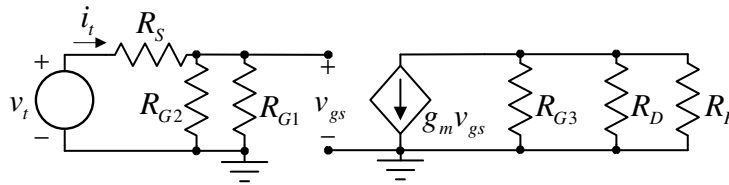


$$g_m = \sqrt{2BI_D} = 0,5\text{mS}$$

$$\left. \begin{aligned} v_p &= -g_m v_{gs} (R_D \parallel R_P \parallel R_{G3}) \\ v_{gs} &= \frac{R_{G1} \parallel R_{G2}}{R_S + R_{G1} \parallel R_{G2}} v_u \end{aligned} \right\} \Rightarrow v_p = -g_m \frac{R_{G1} \parallel R_{G2}}{R_S + R_{G1} \parallel R_{G2}} (R_D \parallel R_P \parallel R_{G3}) v_u \Rightarrow$$

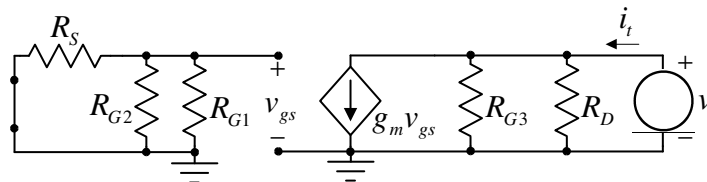
$$a_v = \frac{v_p}{v_u} = -g_m \frac{R_{G1} \parallel R_{G2}}{R_S + R_{G1} \parallel R_{G2}} (R_D \parallel R_P \parallel R_{G3}) \Rightarrow \boxed{a_v = -8,116}$$

Šema za računanje ulazne otpornosti:



$$v_t = (R_S + R_{G1} \parallel R_{G2})i_t \Rightarrow R_{ul} = \frac{v_t}{i_t} = R_S + R_{G1} \parallel R_{G2} \Rightarrow \boxed{R_{ul} = 1,01\text{M}\Omega}$$

Šema za računanje otpornosti koju vidi potrošač:



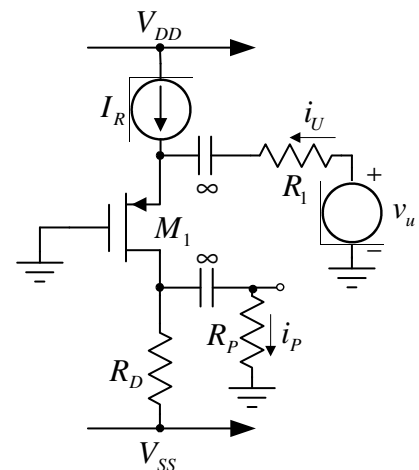
$$v_{gs} = 0 \Rightarrow g_m v_{gs} = 0 \Rightarrow v_t = (R_D \parallel R_{G3})i_t \Rightarrow R_{izl} = \frac{v_t}{i_t} = R_D \parallel R_{G3} \Rightarrow \boxed{R_{izl} = 19,61\text{k}\Omega}$$

**95.** U pojačavaču sa slike parametri tranzistora su:  $V_{TP} = -V_T = -1\text{V}$  i  $B = 1\text{mA/V}^2$ , dok je  $V_{DD} = -V_{SS} = 10\text{V}$ ,  $R_1 = 250\ \Omega$ ,  $R_D = 2\text{k}\Omega$ ,  $R_P = 6\text{k}\Omega$  i  $I_R = 2\text{mA}$ .

a) Odrediti jednosmerne vrednosti napona na drejnu i sorsu, kao i jednosmernu struju drejna tranzistora.

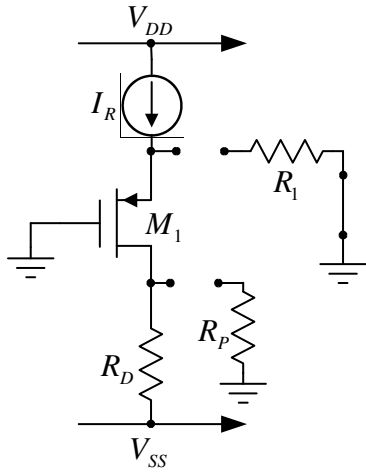
b) Odrediti strujno pojačanje pojačavača  $a_i = i_p / i_u$ .

c) Odrediti otpornosti koje vide ulazni generator i potrošač.



**Rešenje:**

a) DC analiza:



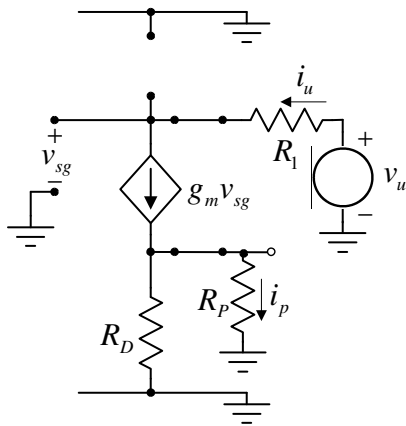
$$I_D = I_R \Rightarrow I_D = 2\text{mA}$$

$$V_D = V_{SS} + R_D I_D \Rightarrow V_D = -6\text{V}$$

$$V_{SG} = \sqrt{\frac{2I_D}{B}} + |V_{TP}| \Rightarrow V_{SG} = 3\text{V}$$

$$V_S = V_G + V_{SG} = 0 + V_{SG} \Rightarrow V_S = 3\text{V}$$

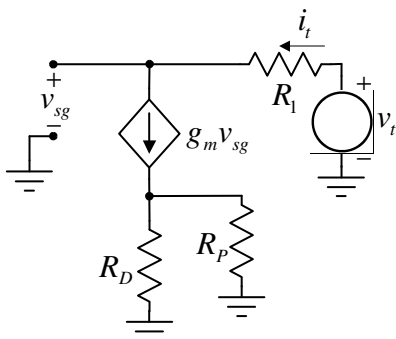
b) AC analiza:



$$g_m = \sqrt{2BI_D} = 2\text{mS}$$

$$i_p = \frac{R_D}{R_D + R_P} i_u \Rightarrow a_i = \frac{i_p}{i_u} = \frac{R_D}{R_D + R_P} \Rightarrow a_i = 0,25$$

c) Šema za računanje ulazne otpornosti:

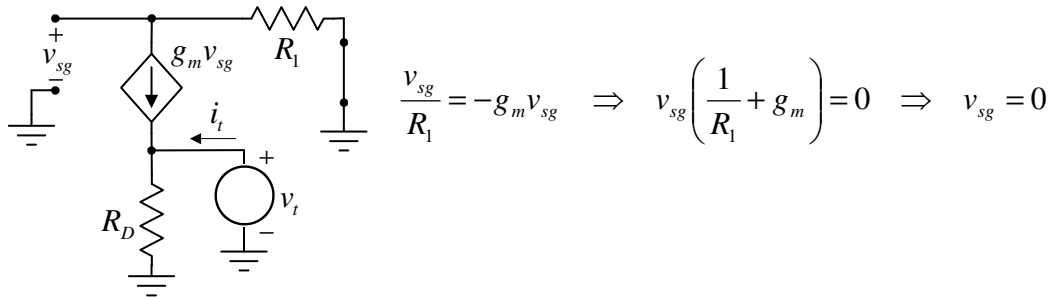


$$i_t = \frac{v_t - v_{sg}}{R_1} \Rightarrow v_{sg} = v_t - R_1 i_t$$

$$i_t = g_m v_{sg} = g_m (v_t - R_1 i_t) \Rightarrow v_t = \left( \frac{1}{g_m} + R_1 \right) i_t$$

$$R_{ul} = \frac{v_t}{i_t} = \frac{1}{g_m} + R_1 \Rightarrow \boxed{R_{ul} = 750\Omega}$$

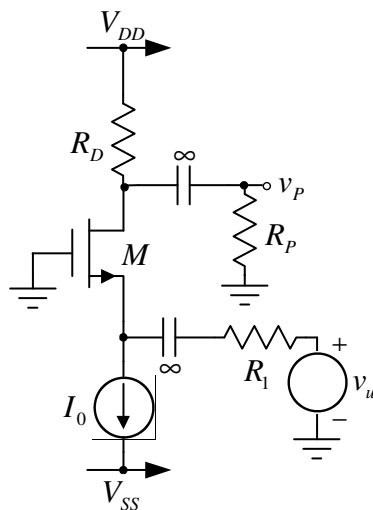
Šema za računanje otpornosti koju vidi potrošač:



$$v_{sg} = 0 \Rightarrow g_m v_{sg} = 0 \Rightarrow v_t = R_D i_t \Rightarrow R_{izl} = \frac{v_t}{i_t} = R_D \Rightarrow \boxed{R_{izl} = 2k\Omega}$$

**96.** (Zadatak za vežbu) U pojačavaču sa slike parametri tranzistora su:  $B = 1 \text{ mA/V}^2$  i  $V_T = 1 \text{ V}$ , dok je:  $V_{DD} = -V_{SS} = 10 \text{ V}$ ,  $R_1 = 250\Omega$ ,  $R_D = 10k\Omega$ ,  $R_P = 30k\Omega$  i  $I_0 = 500 \mu\text{A}$ .

- Odrediti jednosmerne vrednosti napona na sorsu i drejnu, kao i jednosmernu struju drejna.
- Odrediti naponsko pojačanje pojačavača  $a = v_p / v_u$ .
- Odrediti ulaznu otpornost i otpornost koju vidi potrošač  $R_P$ .



**Rešenje:**

a)  $I_D = 500\mu\text{A}$

$V_D = 5\text{V}$

$V_S = -2\text{V}$

b)  $a_v = \frac{v_p}{v_u} = \frac{g_m(R_D \parallel R_P)}{1 + g_m R_1} \Rightarrow a_v = 6$

c)  $R_{ul} = R_1 + \frac{1}{g_m} \Rightarrow R_{ul} = 1,25\text{k}\Omega$

$R_{izl} = R_D \Rightarrow R_{izl} = 10\text{k}\Omega$

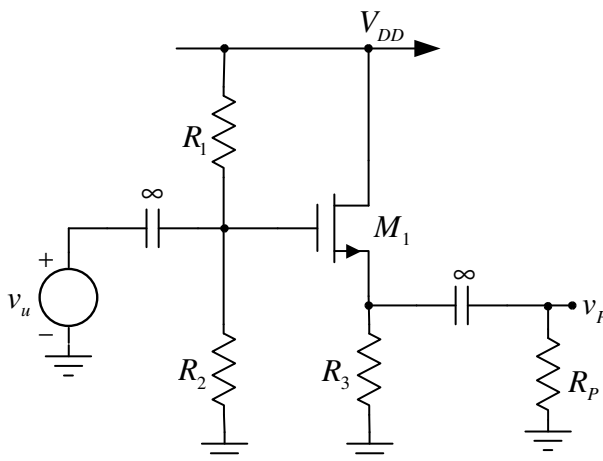
97. (Zadatak za vežbu) U pojačavaču sa slike, parametri tranzistora su:  $V_T = 1\text{V}$ ,

$B = \frac{\mu_n C_{ox} W}{L} = 1 \frac{\text{mA}}{\text{V}^2}$ , dok je:  $V_{DD} = 5\text{V}$ ,  $R_1 = 128\text{k}\Omega$ ,  $R_3 = 10\text{k}\Omega$  i  $R_P = 20\text{k}\Omega$ . Odrediti:

a) Otpornost  $R_2$  tako da jednosmerni napon na sorsu bude  $V_S = \frac{V_{DD}}{2}$ ;

b) Naponsko pojačanje pojačavača  $a_v = \frac{v_p}{v_u}$ ;

c) Ulaznu otpornost i otpornost koju vidi potrošač.





**Rešenje:**

a)  $R_2 = 680\text{k}\Omega$

b)  $a_v = \frac{v_p}{v_u} = \frac{g_m(R_3 \parallel R_p)}{1 + g_m(R_3 \parallel R_p)} \Rightarrow a_v = 0,825$

c)  $R_{ul} = R_1 \parallel R_2 \Rightarrow R_{ul} = 107,7\text{k}\Omega$

$R_{izl} = R_3 \parallel \frac{1}{g_m} \Rightarrow R_{izl} = 1,24\text{k}\Omega$

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## OSNOVI DIGITALNE ELEKTRONIKE (13S042ODE)

- Izborni predmet u na drugoj godini (u četvrtom semestru) Odseka za softversko inženjerstvo (6 kredita)
- Predavanja (2 časa nedeljno): dr Milan Ponjavić
- Računske vežbe (2 časa nedeljno): mr Goran Savić
- Detaljnije informacije i prezentacija predmeta na sajtu: <http://tnt.etf.rs/~si2ode>

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